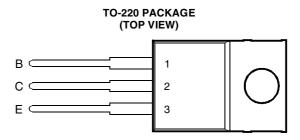


- Designed for Complementary Use with BDW54, BDW54A, BDW54B, BDW54C and BDW54D
- 40 W at 25°C Case Temperature
- 4 A Continuous Collector Current
- Minimum h<sub>FE</sub> of 750 at 3V, 1.5 A



Pin 2 is in electrical contact with the mounting base.

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# absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	BDW53		45	
	BDW53A		60	
Collector-base voltage (I <sub>E</sub> = 0)	BDW53B	$V_{CBO}$	80	V
	BDW53C		100	
	BDW53D		120	
	BDW53		45	
	BDW53A		60	
Collector-emitter voltage (I <sub>B</sub> = 0) (see Note 1)	BDW53B	$V_{CEO}$	80	V
	BDW53C		100	
	BDW53D			
Emitter-base voltage		V <sub>EBO</sub>	5	V
Continuous collector current	I <sub>C</sub>	4	Α	
Continuous base current	I <sub>B</sub>	50	mA	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)	P <sub>tot</sub>	40	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note	P <sub>tot</sub>	2	W	
Unclamped inductive load energy (see Note 4)	½LI <sub>C</sub> <sup>2</sup>	25	mJ	
Operating junction temperature range	T <sub>j</sub>	-65 to +150	°C	
Operating temperature range	T <sub>stg</sub>	-65 to +150	°C	
Operating free-air temperature range	T <sub>A</sub>	-65 to +150	°C	

NOTES: 1. These values apply when the base-emitter diode is open circuited.

- 2. Derate linearly to 150°C case temperature at the rate of 0.32 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 5 mA,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.



# electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS				MIN	TYP	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA	I <sub>B</sub> = 0	(see Note 5)	BDW53 BDW53A BDW53B BDW53C	45 60 80 100			V
I <sub>CEO</sub>	Collector-emitter cut-off current	V <sub>CE</sub> = 60 V	$I_{B} = 0$		BDW53D BDW53 BDW53A BDW53B BDW53C BDW53D	120		0.5 0.5 0.5 0.5 0.5	mA
Ісво	Collector cut-off current	$V_{CB} = 45 \text{ V}$ $V_{CB} = 60 \text{ V}$ $V_{CB} = 80 \text{ V}$ $V_{CB} = 100 \text{ V}$	I <sub>E</sub> = 0	$T_{C} = 150^{\circ}\text{C}$	BDW53 BDW53A BDW53B BDW53C BDW53D BDW53 BDW53A BDW53B BDW53C BDW53D			0.2 0.2 0.2 0.2 0.2 5 5 5	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0					2	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 3 V$ $V_{CE} = 3 V$	$I_{C} = 1.5 A$ $I_{C} = 4 A$	(see Notes 5 and 6)		750 100		20000	l
V <sub>BE(on)</sub>	Base-emitter voltage	V <sub>CE</sub> = 3 V	I <sub>C</sub> = 1.5 A	(see Notes 5 and 6)				2.5	<b>V</b>
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	$I_B = 30 \text{ mA}$ $I_B = 40 \text{ mA}$	$I_{C} = 1.5 A$ $I_{C} = 4 A$	(see Notes 5 and 6)				2.5 4	٧
V <sub>EC</sub>	Parallel diode forward voltage	I <sub>E</sub> = 4 A	I <sub>B</sub> = 0					3.5	V

NOTES: 5. These parameters must be measured using pulse techniques,  $t_0 = 300 \mu s$ , duty cycle  $\leq 2\%$ .

## thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			3.125	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

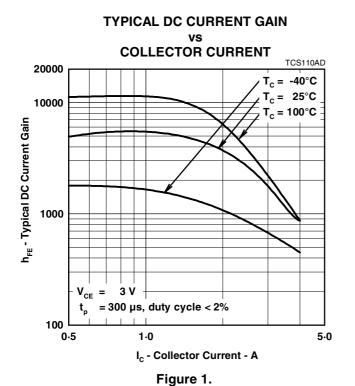
# resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t <sub>on</sub>	Turn-on time	I <sub>C</sub> = 2 A	$I_{B(on)} = 8 \text{ mA}$	$I_{B(off)} = -8 \text{ mA}$		1		μs
t <sub>off</sub>	Turn-off time	$V_{BE(off)} = -5 V$	$R_L = 15 \Omega$	$t_p$ = 20 $\mu s$ , $dc \le 2\%$		4.5		μs

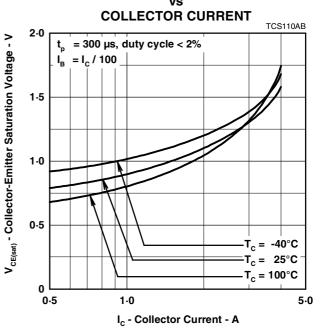
<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>6.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

## **TYPICAL CHARACTERISTICS**



# COLLECTOR-EMITTER SATURATION VOLTAGE



## Figure 2.

#### **BASE-EMITTER SATURATION VOLTAGE**

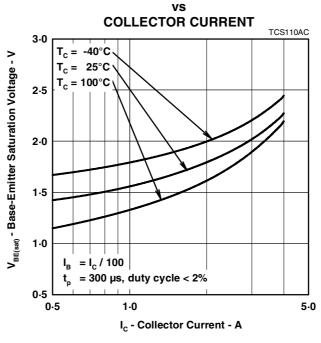
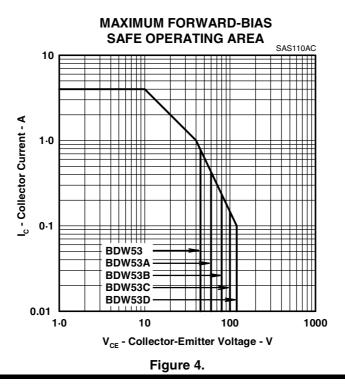


Figure 3.

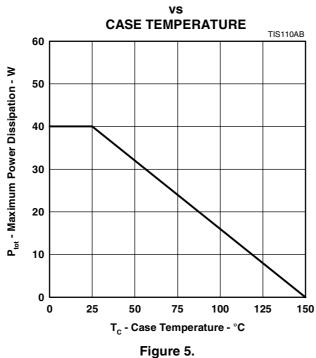
## PRODUCT INFORMATION

# **MAXIMUM SAFE OPERATING REGIONS**



# THERMAL INFORMATION

## **MAXIMUM POWER DISSIPATION**



## PRODUCT INFORMATION